

SANYO Semiconductors

DATA SHEET

Monolithic Digital IC

An ON Semiconductor Company

LB1836M

Low-Saturation Bidirectional Motor Driver for Low-Voltage Drive

Overview

The LB1836M is a low-saturation two-channel bidirectional motor driver IC for use in low-voltage applications. The LB1836M is a bipolar stepper-motor driver IC that is ideal for use in printers, FDDs, cameras and other portable devices.

Features

- Low voltage operation (2.5V min)
- Low saturation voltage (upper transistor + lower transistor residual voltage; 0.40V typ at 400mA).
- Parallel connection (Upper transistor + lower transistor residual voltage; 0.5V typ at 800mA).
- Separate logic power supply and motor power supply
- Brake function
- Spark killer diodes built in
- Thermal shutdown circuit built in
- Compact package (14-pin MFP)

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		-0.3 to +10.5	V
	V _S max		-0.3 to +10.5	V
Output supply voltage	V _{OUT}		V _S + V _{SF}	V
Input supply voltage	V _{IN}		-0.3 to +10	V
GND pin flow-out current	IGND	Per channel	1.0	А
Allowable power dissipation	Pd max	* Mounted on a board.	800	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

^{*} Mounted on a substrate: 30×30×1.5mm³, glass epoxy board.

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LB1836M

Allowable Operating Ranges at Ta = 25°C

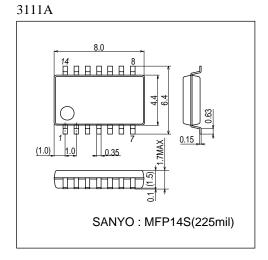
Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		2.5 to 9.0	V
	٧ _S		1.8 to 9.0	V
Input "H"-level voltage	V _{IH}		1.8 to 9.0	V
Input "L"-level voltage	\vee_{IL}		-0.3 to +0.7	V

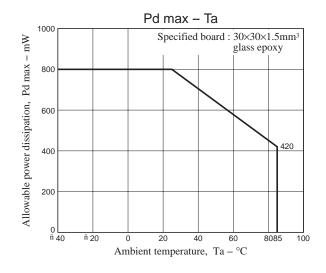
Electrical Characteristics at Ta = 25°C, $V_{CC} = VS = 3V$

Parameter	Cumbal	Conditions		Ratings		
	Symbol	Conditions	min	typ	max	Unit
Supply current	I _{CC} 0	V _{IN} 1, 2, 3, 4 = 0V, I _{CC} + I _S		0.1	10	μΑ
	I _{CC} 1	V _{IN} 1 = 3V, V _{IN} 2, 3, 4 = 0V, I _{CC} + I _S		14	20	mA
	I _{CC} 2	V _{IN} 1, 2 = 3V, V _{IN} 3, 4 = 0V, I _{CC} + I _S		22	35	mA
Output saturation voltage	V _{OUT} 1	I _{OUT} = 200mA		0.20	0.28	V
(upper + lower)	V _{OUT} 2	I _{OUT} = 400mA		0.40	0.60	V
	V _{OUT} 3	I _{OUT} = 400mA, Parallel connection		0.25	0.35	V
	V _{OUT} 4	I _{OUT} = 800mA, Parallel connection		0.50	0.70	٧
Output sustain voltage	V _O (SUS)	I _{OUT} = 400mA	9			V
Input current	I _{IN}	V _{IN} = 2V, V _{CC} = 6V			80	μΑ
Spark killer diode						
Reverse current	I _S (leak)	V _{CC} 1, 2 = 9V			30	μА
Forward voltage	V _{SF}	I _{OUT} = 400mA			1.7	V

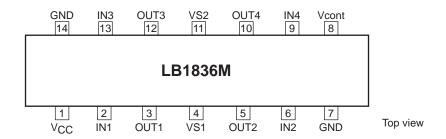
Package Dimensions

unit: mm (typ)



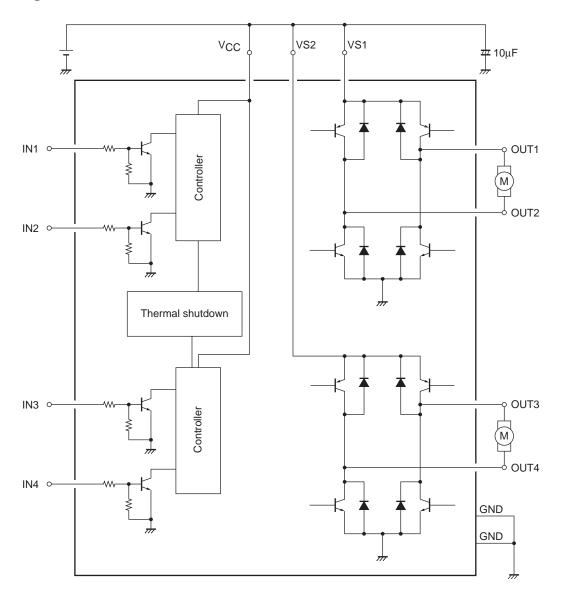


Pin Assignment



Note) Ground both GND pins.

Block Diagram



Truth Table

IN1/3	IN2/4	OUT1/3	OUT2/4	Mode
Н	L	Н	L	Forward
L	Н	L	Н	Reverse
Н	Н	L	L	Brake
L	L	OFF	OFF	Standby

Design Notes

If large current flows on the power supply (V_S) line and the GND line, then in some applications and layouts, misoperation due to line oscillation may result.

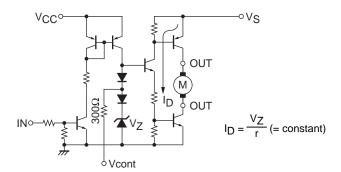
The modes during which large current flows are as follows:

- Motor surge current when the DC motor starts up or when it shifts rotation directions (forward ↔ reverse).
- Passthrough current generated within the IC when shifting rotation directions (forward ↔ reverse) or when shifting from forward/reverse rotation to braking, or vice versa.

The following points should be kept in mind regarding the pattern layout:

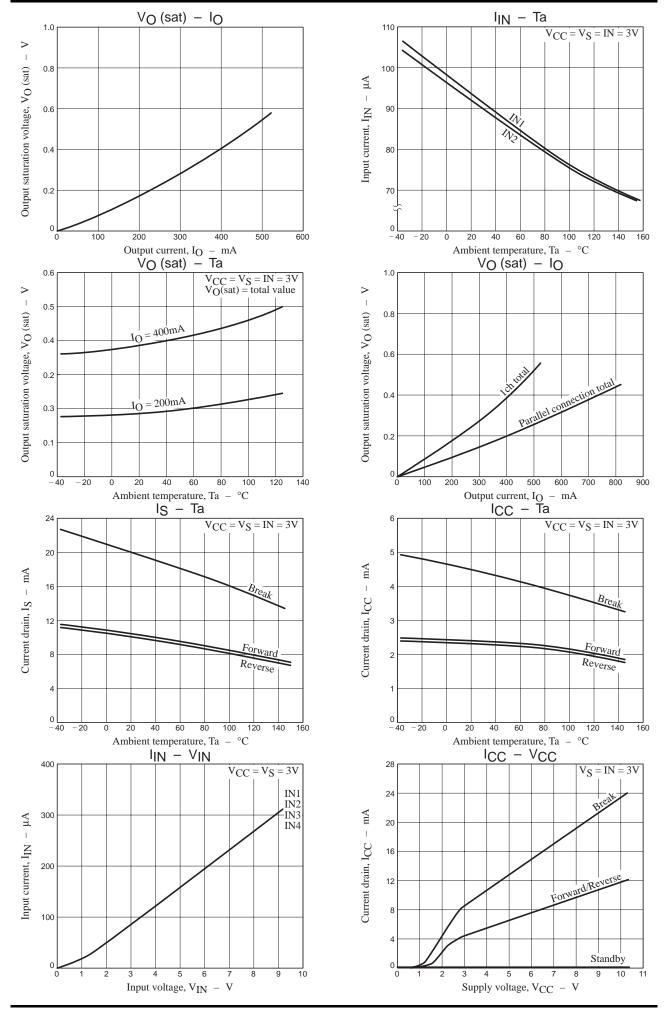
- Keep the wiring lines thick and short in order to reduce wiring inductance between the power supply (VS) and GND.
- Insert a passthrough capacitor near the IC. (Maximum effect is obtained by inserting the passthrough capacitor between VS and the pin 7 GND at the closest distance possible.
- If the CPU and the LB1836M are mounted on separate boards and the difference between the ground potential of each board is large, install resistors of about $10k\Omega$ in series between the CPU and the LB1836M inputs.

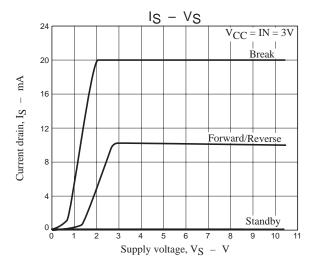
Vcont pin



As shown in the above diagram, the Vcont pin outputs the voltage of the band gap Zener $V_Z + V_F$ (=1.93V). In normal use, this pin is left open.

The drive current ID is varied by the Vcont voltage. However, because the band gap Zener is shared, it functions as a bridge.





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